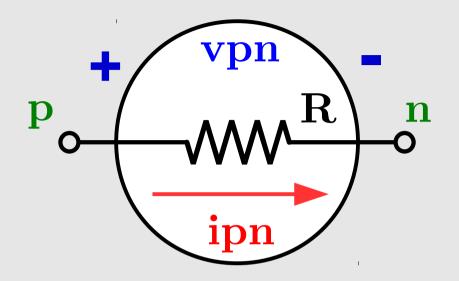
Resistor



name: myR

2 terminals: p, n

branch: pn

I/Os: ipn, vpn

model equation: $\frac{ipn}{R} = \frac{vpn}{R}$

explicit output: ipn

$$\mathbf{ipn} = \frac{d}{dt} (\mathbf{0}) + \frac{\mathbf{vpn}}{\mathbf{R}}$$

$$\mathbf{qe} \quad \mathbf{fe}$$

parameter: R

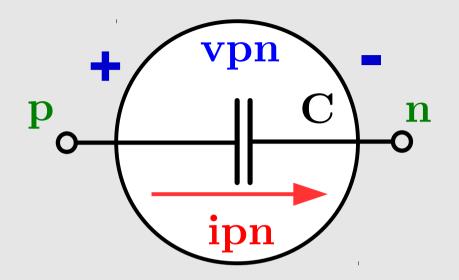
Resistor

define parameter

fill in functions

```
1 function MOD = myR()
       MOD = ee model();
       MOD = add to ee model(MOD, 'name', 'myR');
       MOD = add to ee model(MOD, 'terminals', {'p', 'n'});
       MOD = add to ee model(MOD, 'explicit outs', {'ipn'});
       MOD = add to ee model(MOD, 'parms', {'R', 1000.0});
       MOD = add to ee model(MOD, 'fe', @fe);
10
       MOD = add to ee model(MOD, 'ge', @ge);
11
12
       MOD = finish ee model(MOD);
13 end % myR
14
15 function out = fe(S)
       v2struct(S);
16
17
       ipn fe = vpn/R;
18
19
20
       out(1, 1) = ipn fe;
21 end % fe
22
23 function out = qe(S)
       v2struct(S);
24
25
26
       ipn qe = 0;
27
28
       out(1, 1) = ipn_qe;
29 end % ge
```

Capacitor



name: myC

2 terminals: p, n

branch: pn

I/Os: ipn, vpn

model equation: $ipn = \frac{d}{dt} (C \cdot vpn)$

explicit output: ipn

$$\frac{\mathbf{ipn}}{\mathbf{qe}} = \frac{d}{dt} (\mathbf{C} \cdot \mathbf{vpn}) + \mathbf{0}$$

parameter: C

Capacitor

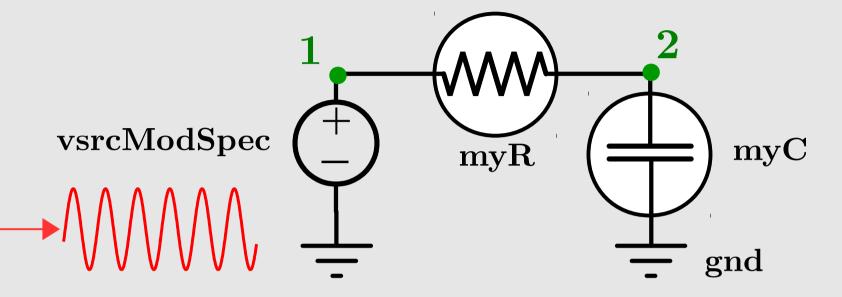
define parameter

fill in functions

```
\mathbf{ipn} = \frac{d}{dt} \left( \mathbf{C} \cdot \mathbf{vpn} \right) + \mathbf{0}
```

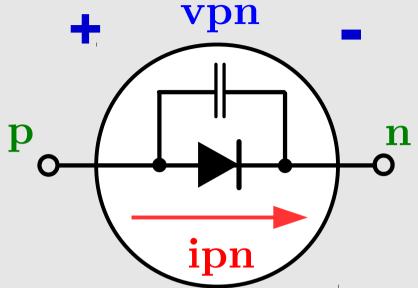
```
1 function MOD = myC()
       MOD = ee model();
       MOD = add to ee model(MOD, 'name', 'myC');
       MOD = add to ee model(MOD, 'terminals', {'p', 'n'});
       MOD = add to ee model(MOD, 'explicit outs', {'ipn'});
       MOD = add to ee model(MOD, 'parms', {'C', 1e-6});
       MOD = add to ee model(MOD, 'fe', @fe);
       MOD = add to ee model(MOD, 'ge', @ge);
10
11
12
       MOD = finish ee model(MOD);
13 end % myC
14
15 function out = fe(S)
       v2struct(S);
16
17
       ipn fe = 0;
18
19
20
       out(1, 1) = ipn fe;
21 end % fe
22
23 function out = qe(S)
       v2struct(S);
25
26
       ipn qe = C*vpn;
27
28
       out(1, 1) = ipn qe;
29 end % ge
```

RC circuit



```
1 function cktnetlist = myRC_ckt()
2    cktnetlist.cktname = 'myRC_ckt';
3    cktnetlist.nodenames = {'1', '2'}; % non-ground nodes
4    cktnetlist.groundnodename = 'gnd';
5
6    cktnetlist = add_element(cktnetlist, myR(), 'R1', {'1', '2'}, {{'R', 1000}});
7    cktnetlist = add_element(cktnetlist, myC(), 'C1', {'2', 'gnd'}, 1e-6);
8
9    mysinfunc = @(t, args) sin(2*pi*1000*t);
10
11    cktnetlist = add_element(cktnetlist, vsrcModSpec(), 'V1', ...
12    {'1', 'gnd'}, {}, {{'DC', 1}, {'AC', 1}, {'TRAN', mysinfunc, []}});
13 end % myRC_ckt
```

Diode



name: diodeC

2 terminals: p, n

branch: pn

I/Os: ipn, vpn

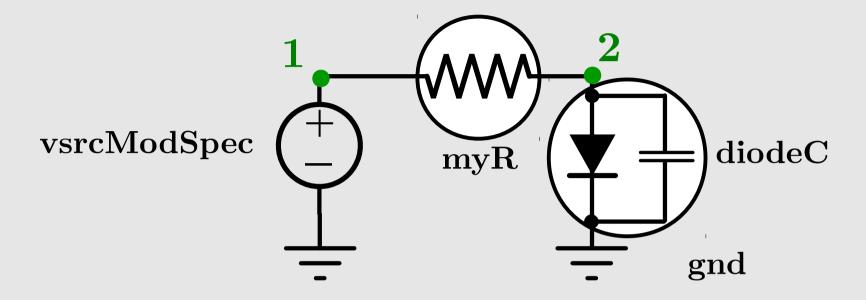
model equation: $ipn = \frac{d}{dt} \left(\mathbf{C} \cdot \mathbf{vpn} \right) + I_S \cdot \left(e^{\frac{\mathbf{vpn}}{\mathbf{V_T}}} - 1 \right)$

$$egin{aligned} \mathbf{ipn} &= rac{d}{dt} \left(\mathbf{qe}
ight) + \mathbf{fe} \ \mathbf{qe} &= \mathbf{C} \cdot \mathbf{vpn} \ \mathbf{fe} &= \mathbf{I_S} \cdot \left(\mathbf{e^{rac{\mathbf{vpn}}{\mathbf{V_T}}}} - 1
ight) \end{aligned}$$

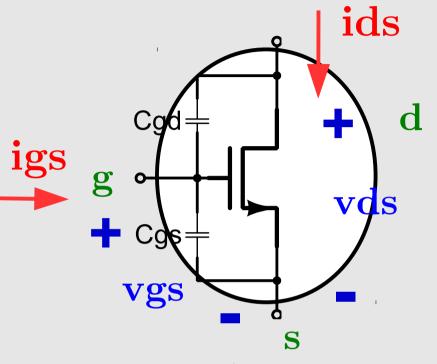
explicit output: ipn

parameters: C, I_S , V_T

Vsrc-R-diode circuit



Schichman-Hodges MOS Model



$$\mathbf{ds_fe} = \begin{cases} 0 \\ \beta \left[(\mathbf{vgs} - V_{th}) - \frac{\mathbf{vds}}{2} \right] \mathbf{vds}, \end{cases}$$

$$igs_fe = 0$$

name: myNMOS

3 terminals: d, g, s

branchs: ds, gs

model equation:

$$\mathbf{ids_fe} = \begin{cases} 0 & \text{if } \mathbf{vgs} \leq V_{th} \\ \beta \left[(\mathbf{vgs} - V_{th}) - \frac{\mathbf{vds}}{2} \right] \mathbf{vds}, & \text{if } \mathbf{vgs} > V_{th} \text{ and } \mathbf{vgs} < \mathbf{vds} + V_{th} \\ \frac{1}{2} \cdot \beta \cdot (\mathbf{vgs} - V_{th})^2, & \text{if } \mathbf{vds} \geq \mathbf{vgs} - V_{th} \end{cases}$$

explicit output: [ids; igs]

parameters: V_{th} , β , Cgs, Cgd